

KB8241

GENERAL PURPOSE
HIGH ISOLATION VOLTAGE
HIGH SENSITIVITY
PHOTOCOUPLER SERIES

FEATURES

1. AC Input.
2. High current transfer ratio.(CTR:Min 600%,at $I_F = \pm 1\text{mA}$, $V_{CE} = 2\text{V}$)
3. High isolation voltage between input and output ($V_{iso} = 5000\text{ Vrms}$)
4. Compact dual-in-line package
KB8241: 2-channel type
5. Recognized by UL and CUL, file NO. E225308
6. RoHS Compliant.

DESCRIPTION

1. The KB8241 (2-channel) is optically coupled isolators containing two GaAs light emitting diode and a darlington silicon phototransistor.
2. The lead pitch is 2.54mm

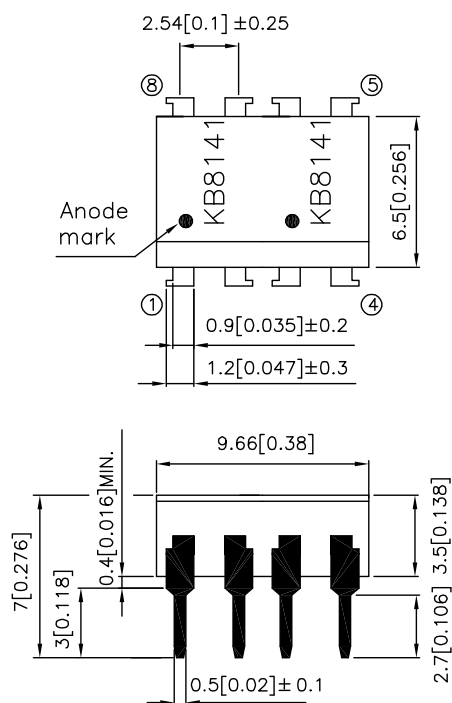
APPLICATIONS

1. Computer terminals
2. Registers, copiers, automatic vending machines
3. System appliances, measuring instruments
4. Programmable logic controller
5. Signal transmission between circuits of different potentials and impedances

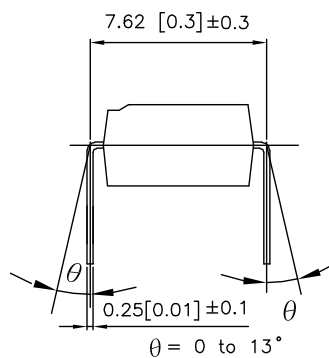
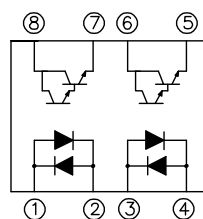
* PACKAGE DIMENSIONS (UNIT: mm)

DIP Type

Top View



Internal connection diagram



① ③ Anode Cathode ⑤ ⑦ Emitter
② ④ Anode Cathode ⑥ ⑧ Collector

TOLERANCE : $\pm 0.5[\pm 0.02]$ UNLESS OTHERWISE NOTED.

* Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I_F	±50	mA
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V_{CEO}	35	V
	Emitter-collector voltage	V_{ECO}	6	V
	Collector current	I_C	80	mA
	Collector power dissipation	P_C	150	mW
Total power dissipation		P _{tot}	200	mW
*1 Isolation voltage		Viso	5000	V _{rms}
Operating temperature		T _{opr}	-30~+100	°C
Storage temperature		T _{stg}	-55~+125	°C
*2 Soldering temperature		T _{sol}	260	°C

*1 40 to 60%RH, AC for 1 minute

*2 For 10 seconds

* Electro-optical Characteristics (Ta=25°C)

Parameter			Symbol	Conditions	Min.	Typ.	Max.	Unit
Input	Forward voltage		V_F	$I_F = \pm 20\text{mA}$	—	1.2	1.4	V
	Peak forward voltage		V_{FM}	$I_{FM} = \pm 0.5\text{A}$	—	—	3.0	V
Output	Collector dark current		I_{CEO}	$V_{CE} = 10\text{V}, I_F = 0\text{mA}$	—	—	10^{-6}	A
Transfer characteristics	*1 Current transfer ratio		CTR	$I_F = \pm 1\text{mA}, V_{CE} = 2\text{V}$	600	—	7500	%
	Collector-emitter saturation voltage		$V_{CE(\text{Sat})}$	$I_F = \pm 20\text{mA}, I_C = 5\text{mA}$	—	0.8	1	V
	Cut-off frequency		f_c	$V_{CE} = 5\text{V}, I_C = 2\text{mA}$ $R_L = 100\Omega, -3\text{dB}$	—	6	—	kHz
	Response time	Rise time	t_r	$V_{CE} = 2\text{V}, I_C = 10\text{mA}$ $R_L = 100\Omega$	—	60	300	μS
		Fall time	t_f		—	53	250	μS

$$*1 \text{ CTR} = \frac{I_C}{I_F} \times 100\%$$

Fig. 1 Current Transfer Ratio vs. Forward Current

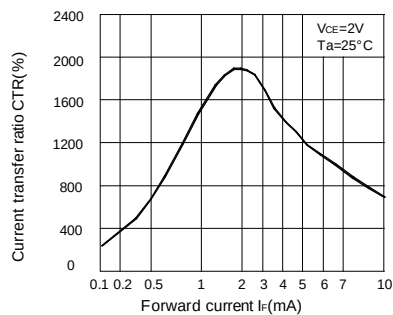


Fig. 2 Forward Current vs. Forward voltage

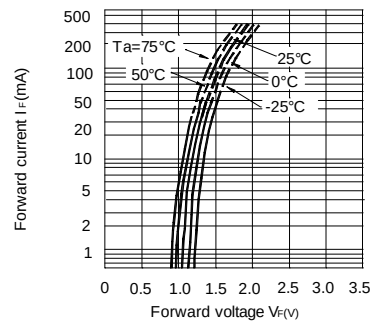


Fig. 3 Collector Current vs. Collector-emitter Voltage

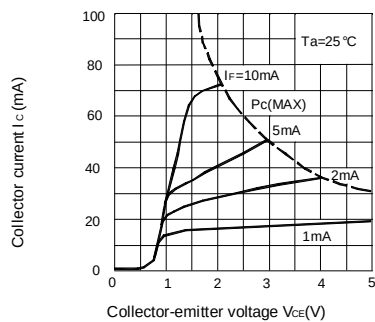


Fig. 4 Relative Current Transfer Ratio vs. Ambient Temperature

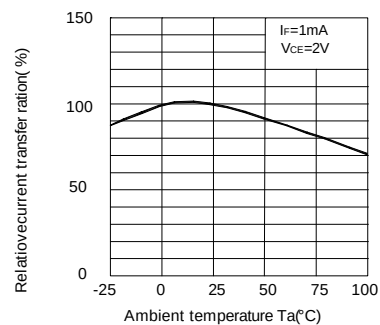


Fig. 5 Collector-emitter Saturation Voltage vs. Ambient Temperature

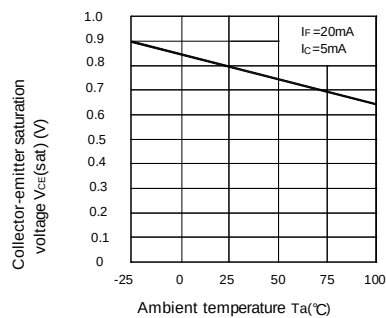


Fig. 6 Collector Dark Current vs. Ambient Temperature

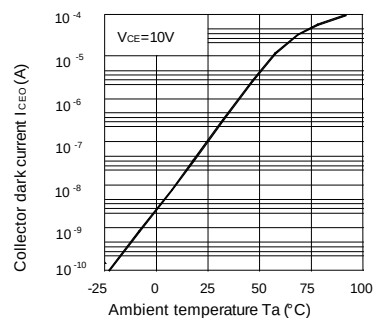


Fig. 7 Forward Current vs. Ambient Temperature

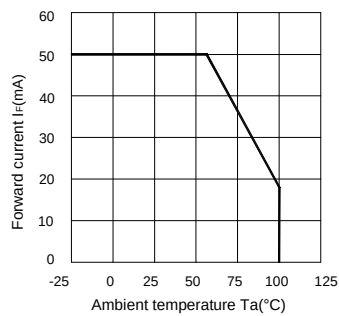


Fig. 8 Collector Power Dissipation vs. Ambient Temperature

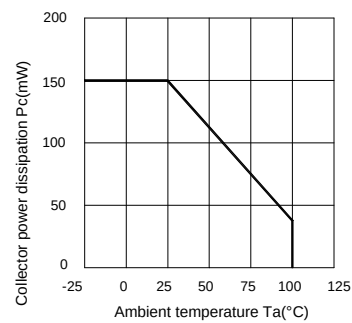
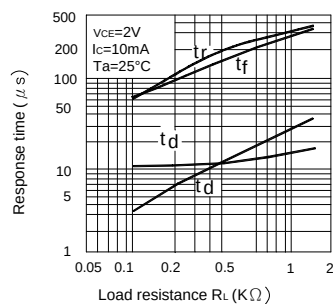


Fig. 9 Response Time vs. Load Resistance



Test Circuit for Response Time

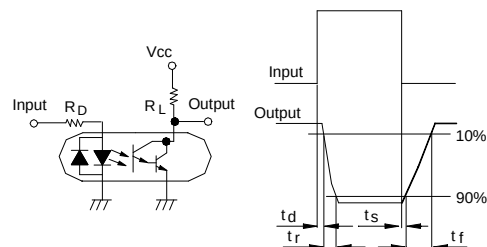
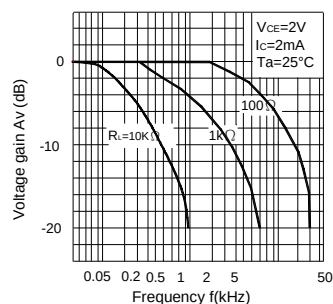


Fig. 10 Frequency Response



Test Circuit for Frequency Response

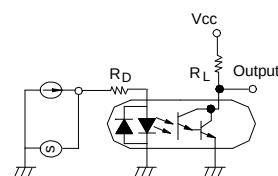
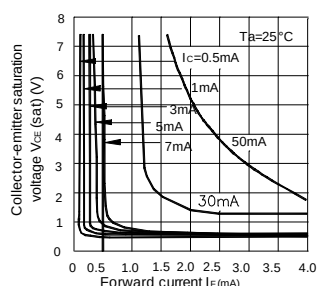


Fig. 11 Collector-emitter Saturation Voltage vs. Forward Current



* NOTES ON HANDLING

1.Recommended soldering conditions (Dip soldering)

(1) Dip soldering

Temperature	260° C or below (molten solder temperature)
Time	Less than 10 seconds.
Cycle	One cycle allowed to be dipped in solder including plastic mold portion.
Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

(2) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2.Cautions regarding noise

Be aware that power is suddenly into the component any surge current may cause damage happen, even if the voltage is within the absolute maximum ratings.

CAUTION

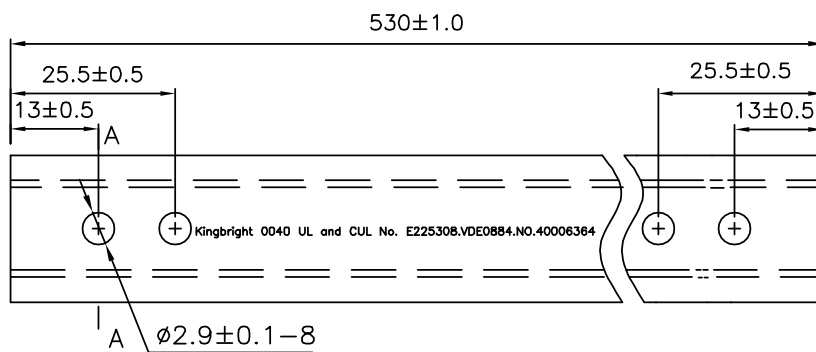
Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them.

RESTRICTIONS ON PRODUCT USE

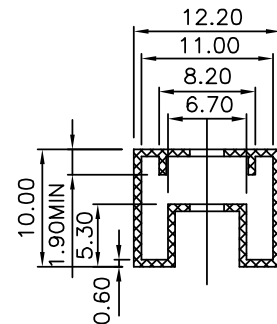
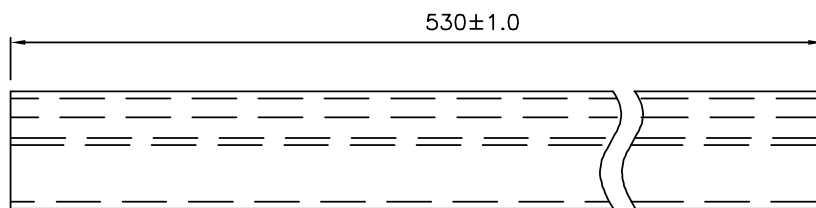
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Dimension of Tube

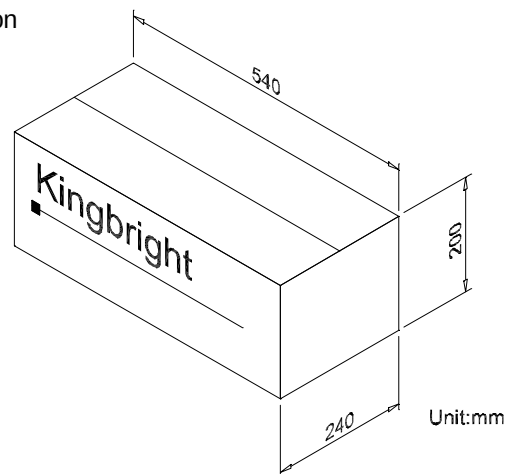
TOLERANCE : $\pm 0.4[\pm 0.012]$ UNLESS OTHERWISE NOTED.
Unit:mm



A-A Side view



Dimension of Carton



Unit:mm

Part Number	Package	Package Style
KB8241	8-pin DIP	50pcs/each tube